



## EFFECT OF POTASSIUM NITRATE IN ZnO NANOPARTICLE SYNTHESIS TO STUDY THE PERFORMANCE OF DYE SENSITIZED SOLAR CELL

Leela Pradhan Joshi<sup>1</sup>, Jeny Bhatta<sup>1</sup>, Tika Bahadur Katuwal<sup>2</sup>, Bhim Prasad Kafle<sup>3</sup>,  
Deependra Das Mulmi<sup>4\*</sup>

<sup>1</sup>Department of Physics, Amrit Campus, Tribhuvan University, Kathmandu, Nepal

<sup>2</sup>Department of Physics, Tri-Chandra Multiple Campus, Tribhuvan University, Kathmandu, Nepal

<sup>3</sup>Department of Chemical Science and Engineering, Kathmandu University, Dhulikhel, Nepal

<sup>4</sup>Nanomaterials Research Laboratory, Nepal Academy of Science and Technology, Khumaltar, Nepal

\*Corresponding author: [deependra.mulmi@nast.gov.np](mailto:deependra.mulmi@nast.gov.np)

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### ABSTRACT

X-ray diffraction, Raman investigations, band gap energy of zinc oxide nanoparticles (ZnO NPs) along with current-voltage characteristic curves of an assembled dye-sensitized solar cell (DSSC) are presented in this article. ZnO NPs were first synthesized with and without potassium nitrate (KNO<sub>3</sub>) salt by precipitation method from precursor solutions of zinc acetate and sodium hydroxide. Then, their thin films were deposited on FTO substrates from the paste made with acetic-acid glacial, and Triton X-100 in ethanol by doctor blade method. The X-ray diffraction (XRD) pattern of ZnO NPs prepared without KNO<sub>3</sub> annealed at 500 °C showed a hexagonal wurtzite structure with preferred orientation along (101) planes and crystallite size of 25 nm. Very similar XRD pattern was found for ZnO NPs prepared with KNO<sub>3</sub>. The crystallite size was found decreased to 17 nm for ZnO NPs made with KNO<sub>3</sub> salt. Raman spectrum of ZnO NPs showed the presence of E<sub>2</sub> high or E<sub>2</sub>(2) peak at 437 cm<sup>-1</sup>. The optical band gaps of the ZnO thin films prepared from ZnO NPs with and without KNO<sub>3</sub> were measured to be of 3.16 eV and 3.26 eV, respectively. After sensitizing the above-prepared ZnO films by dye extract of *Artocarpus lakoocha*, the dye-sensitized solar cells were prepared, and their performance was tested by measuring I-V curves under light illumination of the power density of 1000 W/m<sup>2</sup>. The measurement showed highest I<sub>sc</sub> and V<sub>oc</sub> of 44 μA and 326 mV, respectively.

**Keywords:** Band gap energy, Dye-sensitized solar cell, Raman spectrum, X-ray diffraction, ZnO nanoparticles

### INTRODUCTION

To meet today's high energy demand, research on the fabrication of various types of solar cells has been progressing tremendously. One such type is dye-sensitized solar cell (DSSC) whose fabrication along with its future scope increasing because of its real economic processing cost and less hazardous by-products compared to other silicon-based and thin-film solar cells. In DSSC, the size and the quality of metal oxide semiconducting layer made up of titanium oxide (TiO<sub>2</sub>) or zinc oxide (ZnO) play a vital role in enhancing its performance (Al-Kahlout, 2015). In recent years, zinc oxide nanoparticles (ZnO NPs) have been used as a potential compound semiconducting material in dye-sensitized solar cell technology (Chu *et al.*, 2009; Sharma *et al.*, 2017) because of their excellent properties such as high transparency, large optical band gap (3.3 eV), high electron mobility (100 cm<sup>2</sup>V<sup>-1</sup>s<sup>-1</sup>), large exciton binding energy (60 meV), strong room-temperature uminescence and high chemical and thermal stability (Ghimire *et al.*, 2015; Chen & Lo, 2011; Suh *et al.*, 2007). The ZnO NPs and their corresponding thin films have a large number of applications such as solar cells, veristors, gas sensors, thin-film transistors, UV photodetectors, and light-emitting diodes (Plank *et al.*, 2009; Chatterjee *et al.*,

1999). The ZnO nanoparticles and their thin films can be synthesized employing various processes: sonochemical, solid-state pyrolytic reaction, hydrothermal, magnetron sputtering (Yadav *et al.*, 2008; Wang *et al.*, 2003; Ramimoghadam *et al.*, 2012; Srivastava *et al.*, 2010). One of the most cost-effective and efficient methods is the precipitation method (Ghorbani *et al.*, 2015; Panthi *et al.*, 2018). This article reports on the preparation of ZnO NPs by the precipitation method from the precursor solutions of zinc acetate and sodium hydroxide along with the addition of potassium nitrate to study the additive effect on the crystallite size of ZnO NPs and its impact on the performance of DSSC. The execution of dye-sensitized solar cells was measured using the above-prepared ZnO electrode sensitized by natural dye extract of leaves of *Artocarpus lakoocha* commonly known as monkey fruit collected from Dhangadi, far western part of Nepal.

### MATERIALS AND METHODS

A schematic diagram (Fig. 1) indicates the experimental procedure for the preparation of ZnO NPs. First of all, 0.5 M solution of zinc acetate dihydrated in ethanol was prepared with continuous stirring for 1 h at 60° C for the preparation of precursor-A. Similarly, 0.9 M solution of sodium hydroxide in ethanol (precursor-B) was prepared by stirring continuously for the same period and at same

temperature. After complete dissolution of solutes in their respective solvents, sodium hydroxide solution (B) was added drop-wise in the zinc acetate solution (A), for one hour, with vigorous stirring. The mixture solution of A and B was left overnight to settle zinc hydroxide precipitate. The precipitate was then centrifuged at 1100 rpm for 10 minutes to remove the excess mother liquor. This process was repeated four times, followed by aqueous washing and finally with ethanol to remove any by-product which might have bound to the ZnO NPs. Subsequently, the yield was annealed at high temperature of 500° C for 2 h at which Zn(OH)<sub>2</sub> was decomposed into ZnO NPs.

Following the same procedure, the ZnO NPs was prepared by adding KNO<sub>3</sub> salt solution into the precursor-A with a molar ratio of 1:1 to study the effect of KNO<sub>3</sub> into the ZnO NPs synthesis. A thin layer of ZnO was then deposited on a transparent and conducting fluorine-doped tin oxide (FTO) glass substrates using doctor blade method for which ZnO paste was prepared by mixing above prepared ZnO NPs with acetic acid glacial, Triton X-100 and ethanol under sonication for 15 minutes (Sharma *et al.*, 2017). ZnO films deposited on the FTO substrate were then annealed at two different temperatures, first at 100°C for 30 minutes and then at 450° C for 2 hours.

These samples were characterized using XRD for structural analysis and Raman spectroscopy for optical stability. Bruker D2 Phaser diffractometer, operating at the voltage 30 kV and current 10 mA with X-ray wavelength of CuK<sub>α</sub> (λ=1.54 Å) was employed for XRD analysis in the 2θ ranged from 0° to 80°. The band gap was calculated using the transmittance data captured by UV-visible spectrophotometer (Cary 60; Agilent Technologies). Ultimately, this paper reports the effect of KNO<sub>3</sub> salt in synthesis of ZnO NPs on DSSC performance by measuring the I-V characteristic curves using the Albet Solar Simulator under the illumination of the light of intensity 1000 Watt/m<sup>2</sup>.

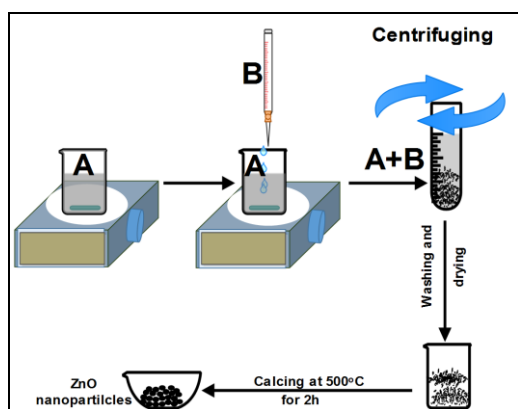


Fig. 1. A schematic diagram for preparation of ZnO nanoparticles

## RESULTS AND DISCUSSION

### XRD Analysis

The XRD patterns of ZnO NPs prepared with and without KNO<sub>3</sub> salt are shown in Figs 2(a) and 2(b), respectively. In both cases, the peaks of ZnO NPs were observed at 2θ = 31.84°, 34.44°, 36.24°, 47.55°, 56.76°, 62.97°, 66.47°, 68.01°, 69.18°, 72.68° and 76.98°. These peaks were indexed to (100), (002), (101), (102), (110), (103), (200), (112), (201), (004) and (202), respectively for ZnO in accordance with JCPDS cards 36-1451 and 89-1397. These observed multiple sharp diffraction peaks illustrate the good crystallinity of as-prepared ZnO NPs. No impurity phases have been observed. From this measurement, it was found that broad and relatively mild peaks were observed for ZnO prepared with KNO<sub>3</sub>. In contrast, sharp and intense peaks were observed in ZnO NPs prepared without KNO<sub>3</sub>. The apparent crystallite size (D) of ZnO was calculated by using Debye-Scherrer's equation (Cullity, 1977; Mulmi *et al.*, 2016).

$$D = \frac{K \times \lambda}{\beta \times \cos \theta} \quad (1)$$

Where, K is the shaping factor (the value 0.9 for ZnO), λ is the wavelength of X-ray used, β is full width at half maximum (FWHM) of the diffracted X-ray peak in radian, and θ is Bragg's angle (Dedova *et al.*, 2007).

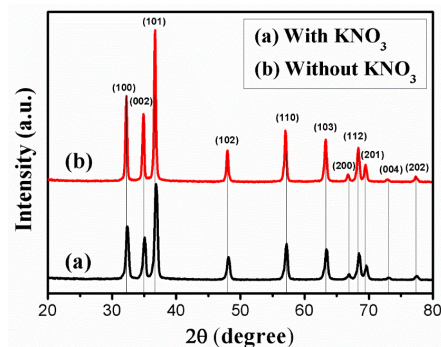


Fig. 2. XRD patterns of ZnO NPs synthesized with (a) and without (b) KNO<sub>3</sub> salt

Since the size and morphology of ZnO are important parameters in determining the physical and physicochemical properties of ZnO (Hu *et al.*, 2003), we have calculated the change in crystallite size of ZnO due to introduction of KNO<sub>3</sub> in the synthesis process. The calculated D corresponding to the most intense peak (101) of ZnO showed a decrease in size from 25 nm to 17 nm when potassium nitrate salt was added into the precursor solution, which was found to be consistent with results of Nejati *et al.* (2011). In the absence of KNO<sub>3</sub>, adsorbed Zn<sup>2+</sup> reacts with OH<sup>-</sup> to form ZnO so that ZnO crystals show growth oriented along c-axis of hexagonal wurtzite structure. When KNO<sub>3</sub> is added into the precursor solution, the ZnO crystal undergoes structure evolution

due to competition of available  $K^+$  ion with  $Zn^{2+}$  that inhibits the adsorption of  $Zn^{2+}$  on this plane, and forced more  $Zn^{2+}$  to be adsorbed onto the six side planes of wurtzite crystal structure of ZnO (Nejati *et al.*, 2011). The change in morphology was accompanied by change in size of ZnO NPs.

### Raman spectroscopy of ZnO NPs

Further, to investigate the optical vibrational properties of the as-prepared ZnO NPs sample, Raman (EnSpectrRaPort Handheld Raman Analyzer-[www.enspectr.com/products/raport-en](http://www.enspectr.com/products/raport-en)) spectroscopic technique was applied. It utilizes a 30  $\mu m$  entrance slit, 1800 g/mm holographic grating, cutting-edge low pass filter, as well as a 30 mW single-mode laser emitting at 532 nm to provide high accuracy Raman measurements in a broad spectral range from 90 to 4000  $cm^{-1}$ . Fig. 3 shows the Raman spectrum of ZnO NPs prepared with  $KNO_3$ . The inset shows the clear presence of  $E_2$  (high) at 437  $cm^{-1}$  (Guo *et al.*, 2009; Fukushima *et al.*, 2017; Khan *et al.* 2015; Srivastava *et al.*, 2010). It has also been reported that the presence of dopants in the ZnO lattice can cause a significant shift in the Raman vibrational frequency of the  $E_2$  (high) mode. According to the literature (Raymond *et al.*, 2017), the combination of acoustic phonons of the  $A_1 + E_2$  is normally detected at about 1101  $cm^{-1}$  in bulk ZnO samples. The Raman spectra of ZnO sample prepared by pneumatic spray pyrolysis technique showed a broad peak from 1017  $cm^{-1}$  to 1207  $cm^{-1}$  which was attributed to the multi-phonon modes (Raymond *et al.*, 2017).

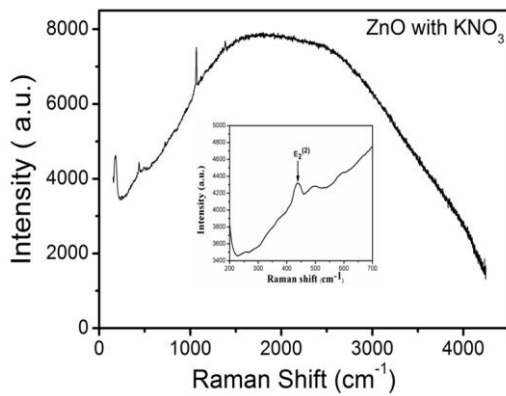


Fig. 3. Raman spectrum of ZnO NPs prepared with  $KNO_3$  salt

### Band gap of ZnO and absorbance of dye extract

The band gap of ZnO film was measured using the transmittance versus wavelength data captured by UV-visible spectrophotometer. In general, the absorption coefficient ( $\alpha$ ) is related to photon energy ( $h\nu$ ) by the known equation as:

$$(\alpha h\nu)^{1/n} = \beta(h\nu - E_g) \quad (2)$$

Where,  $\beta$  is a constant called the band tailing parameter,  $E_g$  is the energy of the optical band gap, and  $n$  is the power factor of the transition mode, which is dependent upon the nature of the material. According to Tauc relation (Tauc & Menth, 1972), the plotting of  $(\alpha h\nu)^2$  versus the photon energy ( $h\nu$ ) gives a straight line in a particular region. The extrapolation of this straight line intercepts the  $(h\nu)$  axis to provide the value of the optical energy gap (Mulmi *et al.*, 2018). Fig. 4 depicts the Tauc plot of ZnO thin films. The calculated band gap energies of ZnO films prepared from ZnO NPs with and without  $KNO_3$  were 3.16 eV and 3.26 eV, respectively, which lie in the range of reported value of ZnO (Al-Kahlout, 2015).

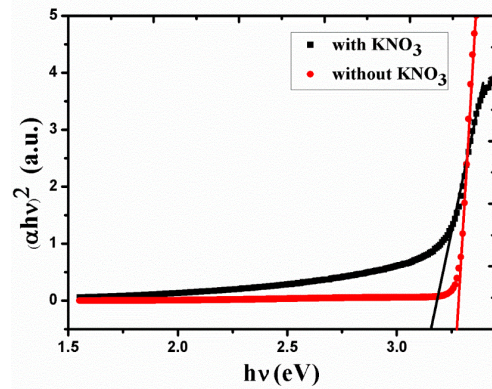


Fig. 4. Tauc plot to calculate the bandgap of ZnO film prepared from ZnO NPs with and without  $KNO_3$

Fig. 5 shows the absorbance of *Artocarpus lakoocha* dye extract prepared in ethanol. It indicates wide absorbance in the visible range with three significant peaks at 280 nm, 465 nm and 656 nm. Hence this dye can absorb UV and visible light thereby increasing the efficiency of the DSSC.

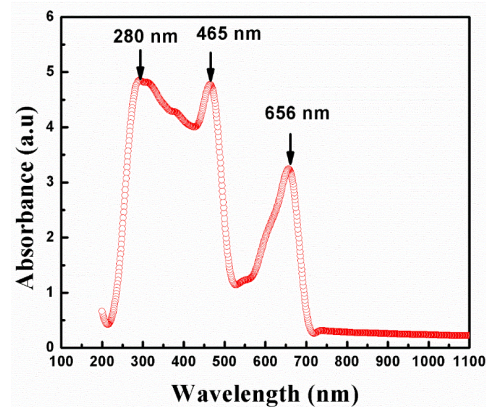
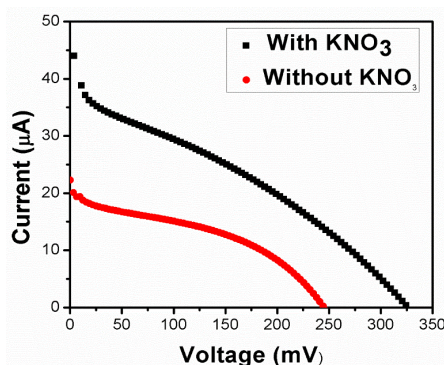


Fig. 5. The absorbance of dye extract of *Artocarpus Lakoocha*

### DSSC performance

The performance of DSSC was tested by measuring I-V curves with Albet Solar Simulator (Bhandari *et al.*, 2017).

Fig. 6 shows the characteristic I-V curves of DSSCs prepared using ZnO films. The ZnO thin film was first sensitized by *Artocarpus lakoochadye* extract at 60° C for an hour and then I-V measurement was taken in the presence of intensity of light 1000 Watt/m<sup>2</sup>. The red circle symbol represents the I-V plot of DSSC prepared from ZnO without additive, and black square symbol represents the I-V plot of DSSC from ZnO NPs prepared with additive KNO<sub>3</sub>. The result showed higher values of short circuit current (I<sub>sc</sub>) of 44 μA and open-circuit voltage (V<sub>oc</sub>) of 326 mV. In conclusion, the presence of KNO<sub>3</sub> enhanced the surface area of ZnO film, which in turn helped in increasing the performance of DSSC.



**Fig. 6. I-V curves of DSSC fabricated from ZnO NPs with and without KNO<sub>3</sub>**

## CONCLUSION

ZnO nanoparticle was successfully synthesized with and without KNO<sub>3</sub> from the precursor mixture of zinc acetate, and sodium hydroxide in ethanol solution by the precipitation method. All the XRD peaks were clear and sharp. This evidence proved that both ZnO NPs were well crystallized. Further, the XRD investigation of the effect of adding KNO<sub>3</sub> salt into the zinc acetate solution showed a decrease in crystallite size of ZnO NPs from 25 nm to 17 nm. The Raman analysis illustrated the presence of E<sub>2</sub> high peak at 437 cm<sup>-1</sup> which confirmed the formation of stable wurtzite structured ZnO. From the optical absorption measurement, it was found that the band gap energy of ZnO NPs with and without KNO<sub>3</sub> were 3.16 eV and 3.26 eV, respectively. The current-voltage analysis of a dye-sensitized solar cell fabricated with photo-electrode prepared with small size ZnO NPs had shown enhancement in short circuit current and open-circuit voltage. The maximum observed I<sub>sc</sub> and V<sub>oc</sub> were of 44 μA and 326 mV, respectively, for ZnO prepared with KNO<sub>3</sub> salt.

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